FREE





# N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}$ ( $\Omega$ )	I <sub>D</sub> (mA)		
60	3 at V <sub>GS</sub> = 10 V	240		

# FEATURES Halogen-free According to IEC 61249-2-21 Definition

Low On-Resistance: 3 Ω
Low Threshold: 2 V (typ.)
Low Input Capacitance: 25 pF

Fast Switching Speed: 7.5 nsLow Input and Output Leakage

• Compliant to RoHS Directive 2002/95/EC

### **BENEFITS**

- Low Offset Voltage
- Low-Voltage Operation
- Easily Driven Without Buffer
- · High-Speed Circuits
- Low Error Voltage

### **APPLICATIONS**

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- · Battery Operated Systems
- · Solid-State Relays

TO-236 (SOT-23)	
G 1 3 D	Marking Code: 7E
Top View	

Ordering Information: 2N7002E-T1-E3 (Lead (Pb)-free)

2N7002E-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	60		
Gate-Source Voltage		V <sub>GS</sub>	± 20	V	
Continuous Drain Current (T <sub>.I</sub> = 150 °C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	240	mA	
Continuous Diain Current (1) = 150 C)	T <sub>A</sub> = 70 °C	סי	190		
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	1300		
Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	0.35	W	
Power Dissipation	T <sub>A</sub> = 70 °C	' D	0.22	VV	
Thermal Resistance, Junction-to-Ambient		R <sub>thJA</sub>	357	°C/W	
Operating Junction and Storage Temperature Range		T <sub>J,</sub> T <sub>stg</sub>	- 55 to 150	°C	

#### Notes

a. Pulse width limited by maximum junction temperature.

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			Limits				
Parameter	Symbol	Test Conditions	Min.	Typ. <sup>a</sup>	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V, } I_{D} = 10  \mu\text{A}$	60	68		V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1	2	2.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 15 \text{ V}$			± 10	nA	
		V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V	1		1		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ = 60 V, $V_{GS}$ = 0 V , $T_{J}$ = 125 °C			500	μA	
On-State Drain Current <sup>b</sup>		V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 7.5 V	800	1300			
	I <sub>D(on)</sub>	V <sub>GS</sub> = 4.5 V, V <sub>DS</sub> = 10 V	500	700		mA	
Drain-Source On-Resistance <sup>b</sup>	В	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 250 mA		1.2	3		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 200 mA		1.8	4	Ω	
Forward Transconductance <sup>b</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 200 mA		600		mS	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = 200 mA, V <sub>GS</sub> = 0 V		0.85	1.2	V	
Dynamic <sup>a</sup>			•		•		
Total Gate Charge	Q <sub>g</sub>	V 40 V V 45 V		0.4	0.6	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}$ $I_{D} \cong 250 \text{ mA}$		0.06			
Gate-Drain Charge	Q <sub>gd</sub>			0.06			
Input Capacitance	C <sub>iss</sub>			21		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		7			
Reverse Transfer Capacitance	C <sub>rss</sub>			2.5			
Switching <sup>a, c</sup>				•			
Turn-On Time	t <sub>d(on)</sub>	$V_{DD}$ = 10 V, $R_L$ = 40 $\Omega$		13	20	ns	
Turn-Off Time	t <sub>d(off)</sub>	$I_D \cong 250 \text{ mA}, V_{GEN} = 10 \text{ V}, R_g = 10 \Omega$		18	25		

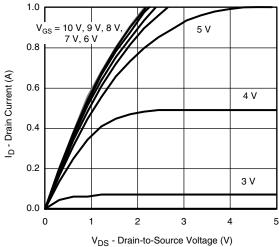
### Notes:

- a. For DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: pulse width  $\leq$  300  $\mu$ s duty cycle  $\leq$  2 %.
- c. Switching time is essentially independent of operating temperature.

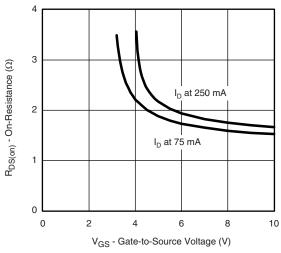
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



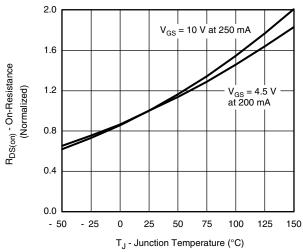
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



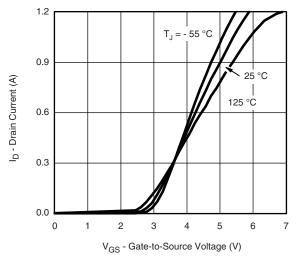




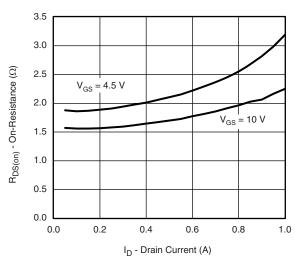
On-Resistance vs. Gate-Source Voltage



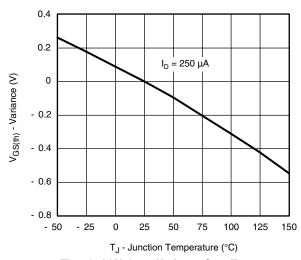
On-Resistance vs. Junction Temperature



**Transfer Characteristics** 



On-Resistance vs. Drain Current

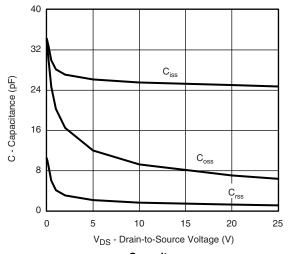


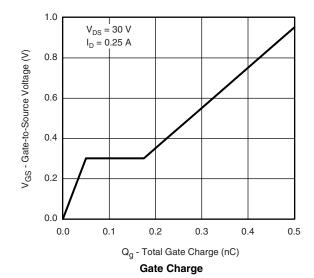
**Threshold Voltage Variance Over Temperature** 

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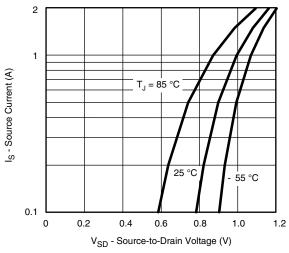
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### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)









Source-Drain Diode Forward Voltage

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg270860">www.vishay.com/ppg270860</a>.

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### SOT-23 (TO-236): 3-LEAD







Dim	MILLIMETERS		INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A <sub>1</sub>	0.01	0.10	0.0004	0.004	
A <sub>2</sub>	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E <sub>1</sub>	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e <sub>1</sub>	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L <sub>1</sub>	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
FCN: S-03946-Rev K 09-	lul-01	•			

ECN: S-03946-Rev. K, 09-Jul-01

DWG: 5479

Document Number: 71196 www.vishay.com 09-Jul-01





# **Mounting LITTLE FOOT® SOT-23 Power MOSFETs**

Wharton McDaniel

Surface-mounted LITTLE FOOT power MOSFETs use integrated circuit and small-signal packages which have been been modified to provide the heat transfer capabilities required by power devices. Leadframe materials and design, molding compounds, and die attach materials have been changed, while the footprint of the packages remains the same.

See Application Note 826, Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs, (http://www.vishay.com/doc?72286), for the basis of the pad design for a LITTLE FOOT SOT-23 power MOSFET footprint. In converting this footprint to the pad set for a power device, designers must make two connections: an electrical connection and a thermal connection, to draw heat away from the package.

The electrical connections for the SOT-23 are very simple. Pin 1 is the gate, pin 2 is the source, and pin 3 is the drain. As in the other LITTLE FOOT packages, the drain pin serves the additional function of providing the thermal connection from the package to the PC board. The total cross section of a copper trace connected to the drain may be adequate to carry the current required for the application, but it may be inadequate thermally. Also, heat spreads in a circular fashion from the heat source. In this case the drain pin is the heat source when looking at heat spread on the PC board.

Figure 1 shows the footprint with copper spreading for the SOT-23 package. This pattern shows the starting point for utilizing the board area available for the heat spreading copper. To create this pattern, a plane of copper overlies the drain pin and provides planar copper to draw heat from the drain lead and start the process of spreading the heat so it can be dissipated into the

ambient air. This pattern uses all the available area underneath the body for this purpose.

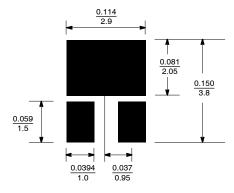


FIGURE 1. Footprint With Copper Spreading

Since surface-mounted packages are small, and reflow soldering is the most common way in which these are affixed to the PC board, "thermal" connections from the planar copper to the pads have not been used. Even if additional planar copper area is used, there should be no problems in the soldering process. The actual solder connections are defined by the solder mask openings. By combining the basic footprint with the copper plane on the drain pins, the solder mask generation occurs automatically.

A final item to keep in mind is the width of the power traces. The absolute minimum power trace width must be determined by the amount of current it has to carry. For thermal reasons, this minimum width should be at least 0.020 inches. The use of wide traces connected to the drain plane provides a low-impedance path for heat to move away from the device.

Document Number: 70739 26-Nov-03



### **RECOMMENDED MINIMUM PADS FOR SOT-23**



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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